In-Situ De-embedding (ISD)

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Outline

- What is causality
- What is In-Situ De-embedding (ISD)
- Comparison of ISD results with simulation and other tools
- How non-causal de-embedding affects connector compliance testing
- How to extract accurate PCB trace attenuation that is free of spikes and glitches
- How to extract a PCB's material property (DK, DF, roughness) by matching all IL, RL, NEXT, FEXT and TDR/TDT of de-embedded PCB traces





VNA and **S** parameter

Vector network analyzer (VNA) is an equipment that launches a sinusoidal waveform into a structure, varies the period (or frequency) of waveform, and lets us observe the transmitted and reflected wave as "frequency-domain response".

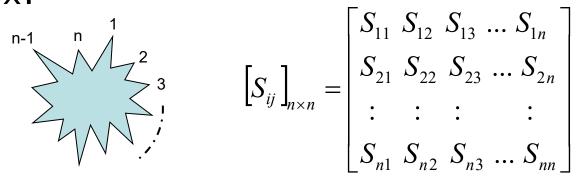
 Such frequency-domain response, when normalized to the incident wave, is called scattering parameter

(or, S parameter).

T (period) f (frequency) = 1/T f (frequency) = 1/T f (frequency) = 1/T

What is S parameter

For an n-port (or I/O) device, S parameter is an n x n matrix:



- S_{ij} is called the S parameter from Port j to Port i.
- S_{ij} has a unique property that its magnitude is less than or equal to 1 (or, 0 dB) for a passive device.

$$\left|S_{ij}\right| \le 1$$

$$S_{ij}(dB) = 20 \times \log_{10}\left|S_{ij}\right| \le 0 \ dB$$





What is a Touchstone (.sNp) file

 S parameter at each frequency is expressed in Touchstone file format.

```
in dB and
in GHz
                               Reference
                 phase angle
       S param
                               impedance
    Total number of ports = 4
    Total number of frequency points = 800
  # GHZ
        S DB
               R 50
                              -41.40676 79.91354
                                                   -0.08648679 -6.544144
  0.025
                    48.77486
         -36.59296
                                                                                       -105.618
                              -36.35592
                                         51.52433
                                                                                      -6.527076
                                                             -105.5124
          -0.08421237 -6.537903 -49.44814
                                                                                      79.91856
                                             -105.644
                                                       -36.0317
                                             -6.542909
                                                       -41.36758
        -32.22576
                                        74.15976
                                                   -0.1277169
                                                               -12.82876
                             -32.12694
                                         50.92389
                                                   -43.90926
                                                              -112.0764
                                                                                     -12.7985
                    74.16304
                                                                          -0.132402
          -0.1242117 -12.82302 -43.89
                                       -112.0248
                                                   -32.10987
                                                               50.3115
                                                                       -35.56998
         -43.88424 -112.0517 -0.1381616
                                          -12.80199 -35.56758 74.06782
                                                                            -31.94136
                                                                                       50.49276
  0.075
         -29.88861 42.02766 -32.19713
                                         68.06704
                                                   -0.1589249
                                                                -19.05252
                                                                           -40.67476
          -32.19116 68.0941
                                                  -40.63857
         -0.1603356 -19.0376
                                          -118.8543
                                                     -29.89064
          -40.65711 -118.8021
                               -0.1737256
                                           -19.02956 -32.16865
                                                                  67.93389
                                                                            -29.65444
```

Frequency in GHz

S11, S12, ..., S44 in dB and phase angle





What is causality

cau·sal·i·ty

/kô'zalədē/

noun

- 1. the relationship between cause and effect.
- 2. the principle that everything has a cause.

In other words:

Can not get something from nothing.

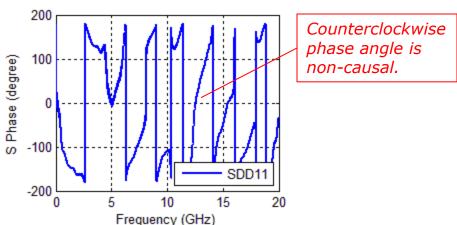




How to identify non-causal S parameter

Convert S parameter into TDR/TDT. Response before time zero* and/or after DUT is non-causal. 110 105 Z (Ohm) 100 S (dB) * Delay waveform by 1ns to see if tools -30 do not show before 90 time zero. SDD11 TDD11 -40 85 10 20 15 Frequency (GHz) Time (ns) 200 Counterclockwise

Check phase angle.







Why does S parameter violate causality

- Measurement error (de-embedding), simulation error (material property) and finite bandwidth of S parameter all contribute to non-causality.
- Kramers-Kronig relations require that the real and imaginary parts of an analytic function be related to each other through Hilbert transform:

$$\Psi(\omega) = \Psi_{R}(\omega) + j\Psi_{I}(\omega)$$

$$\Psi_{R}(\omega) = \frac{1}{\pi} P \int_{-\infty}^{\infty} \frac{\Psi_{I}(\omega')}{\omega' - \omega} d\omega'$$

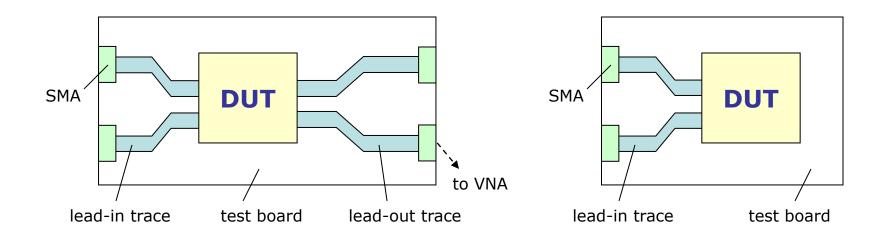
$$\Psi_{I}(\omega) = -\frac{1}{\pi} P \int_{-\infty}^{\infty} \frac{\Psi_{R}(\omega')}{\omega' - \omega} d\omega'$$





What is de-embedding

 To remove the effect of fixture (SMA connector + lead-in/out) and extract the S parameter of DUT (device under test).



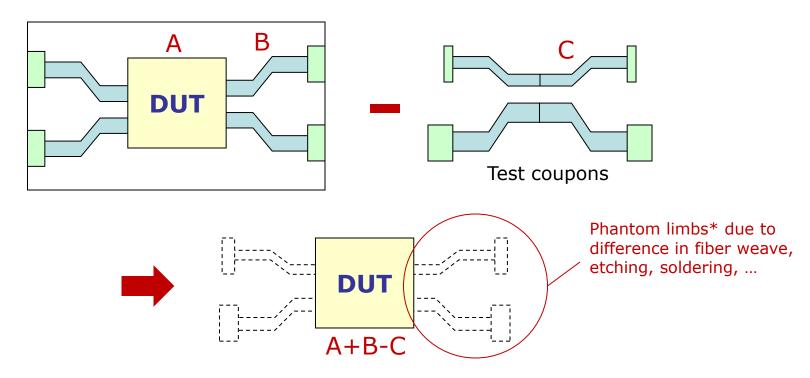
- The lead-ins and lead-outs don't need to look the same.
- There may even be no lead-outs (e.g., package).





Why do most de-embedding tools give causality error

 Most tools use test coupons directly for deembedding, so difference between actual fixture and test coupons gets piled up into DUT results.



^{*} http://www.edn.com/electronics-blogs/test-voices/4438677/Software-tool-fixes-some-causality-violations by Eric Bogatin



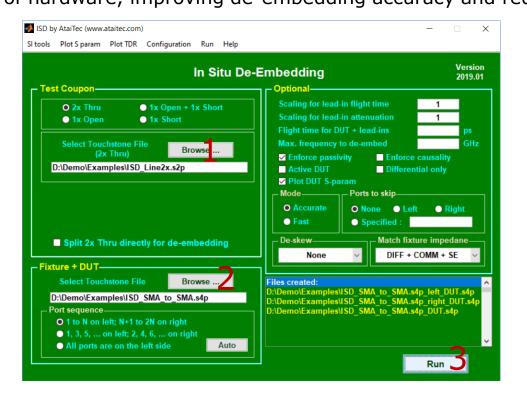
What is In-Situ De-embedding (ISD) Introduced to address impedance variation

 ISD uses test coupon ("2x thru" or "1x open / 1x short") as reference and de-embeds fixture's actual impedance through numerical optimization.

 Other methods use test coupon directly for de-embedding and result in causality error when test coupon and actual fixture to be de-embedded have different impedance.

 ISD addresses impedance variation between test coupon and actual fixture through software, instead of hardware, improving de-embedding accuracy and reducing

hardware cost.







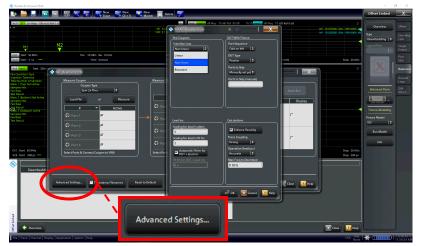
ISD is integrated into R&S ZNB



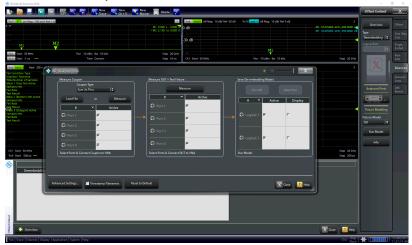
Launching ISD model



Advanced settings



ISD start-up



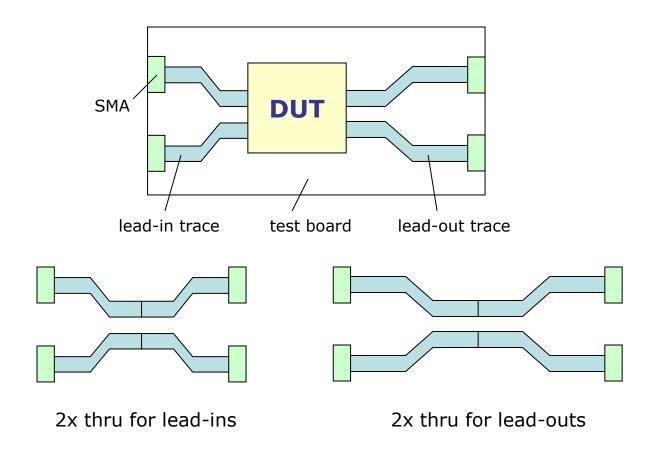
Running





What is "2x thru"

"2x thru" is 2x lead-ins or lead-outs.

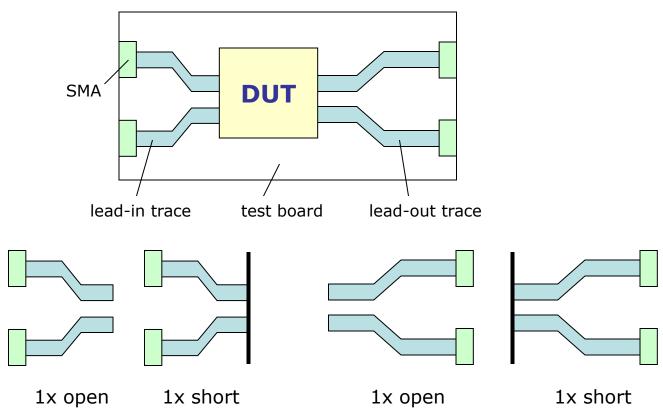


2 sets of "2x thru" are required for asymmetric fixture.



What is "1x open / 1x short"

"1x open / 1x short" is useful when "2x thru" is not possible (e.g., connector vias, package, ...).

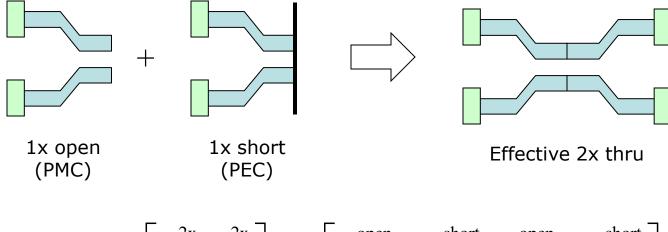






What is "1x open + 1x short"

"1x open + 1x short" can be equated to effective* 2x thru.



$$\left[S\right]^{2x} = \begin{bmatrix} S_{11}^{2x} & S_{12}^{2x} \\ S_{12}^{2x} & S_{11}^{2x} \end{bmatrix} = \frac{1}{2} \begin{bmatrix} S_{11}^{\text{open}} + S_{11}^{\text{short}} & S_{11}^{\text{open}} - S_{11}^{\text{short}} \\ S_{11}^{\text{open}} - S_{11}^{\text{short}} & S_{11}^{\text{open}} + S_{11}^{\text{short}} \end{bmatrix}$$

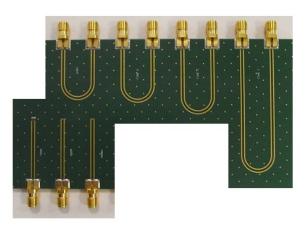
^{*} C.C. Huang, "Fixture de-embedding using calibration structures with open and short terminations," US patent no. 9,797,977, 10/24/2017.





Why ISD is more accurate and saves \$\$\$

TRL calibration board



- More board space Multiple test coupons are required.
- Test coupons are used directly for deembedding.
- All difference between calibration and actual DUT boards gets piled up into DUT results.
- Expensive SMAs, board materials (Roger) and tight-etching-tolerance are required.
 - Impossible to guarantee all SMAs and traces are identical (consider weaves, etching, ...)
- Time-consuming manual calibration is required.
 - Reference plane is in front of DUT.

ISD test coupon

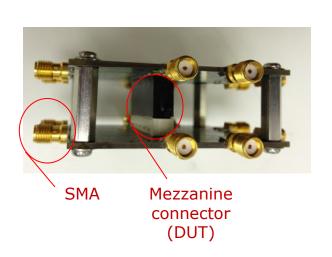


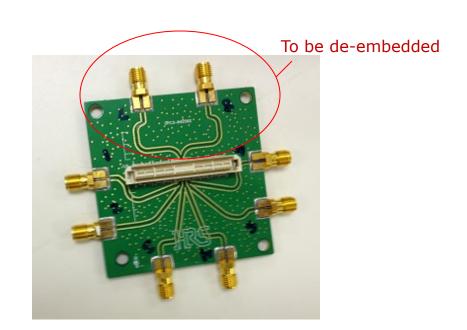
- Only one 2x thru test coupon is needed.
- Test coupon is used only for reference, not for direct de-embedding.
- Actual DUT board impedance is deembedded.
- Inexpensive SMAs, board materials (FR4) and loose-etching-tolerance can be used.
- ECal can be used for fast SOLT calibration.
 - Reference plane is in front of SMA.
 - De-embedding requires only two input files:
 2x thru and DUT board (SMA-to-SMA)
 Touchstone files.
 - More information: Both de-embedding and DUT files are provided as outputs.



Example 1: Mezzanine connector *ISD vs. TRL*

 In this example, we will use ISD and TRL to extract a mezzanine connector and compare their results.





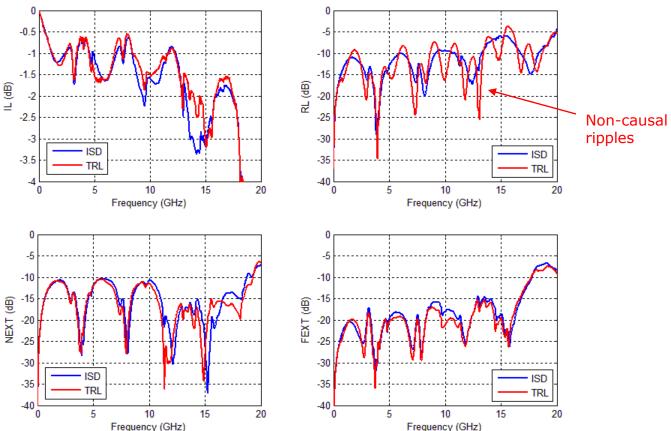
*Courtesy of Hirose Electric





DUT results after ISD and TRLWhich one is more accurate?

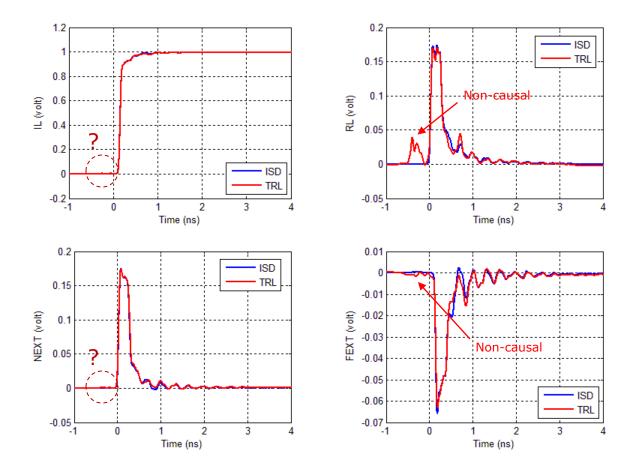
TRL gives too many ripples in return loss (RL) for such a small DUT.

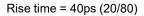






Converting S parameter into TDR/TDT shows non-causality in TRL results



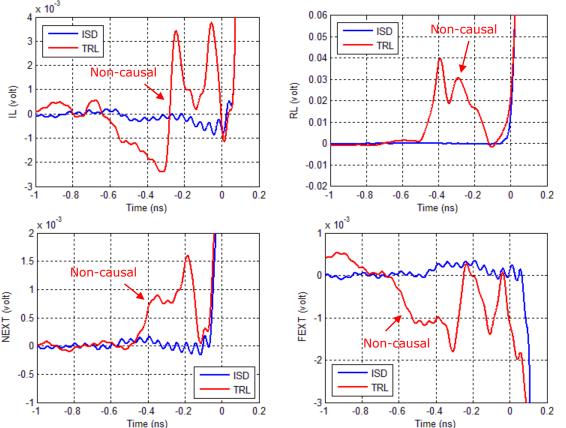






Zoom-in shows non-causal TRL results in all IL, RL, NEXT and FEXT

TRL causes time-domain errors of 0.38% (IL), 25.81% (RL), 1.05% (NEXT) and 2.86% (FEXT) in this case*.



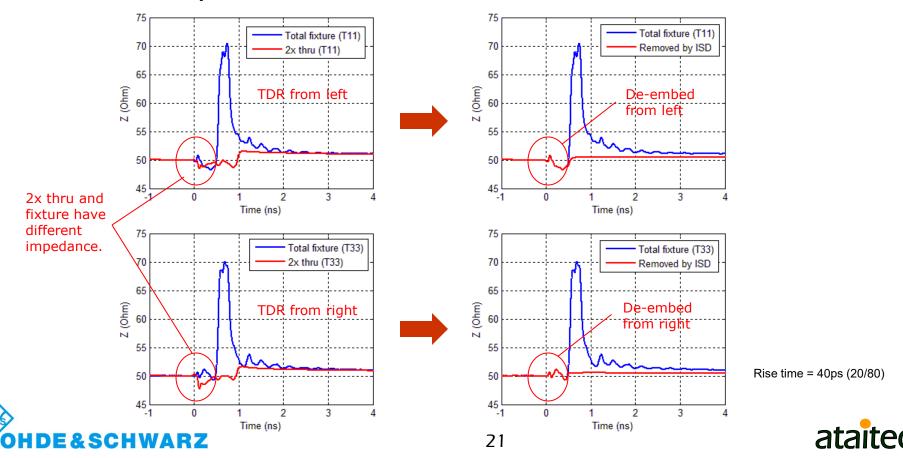
* The percentage is larger with single-bit response and/or faster rise time.

Rise time = 40ps (20/80)



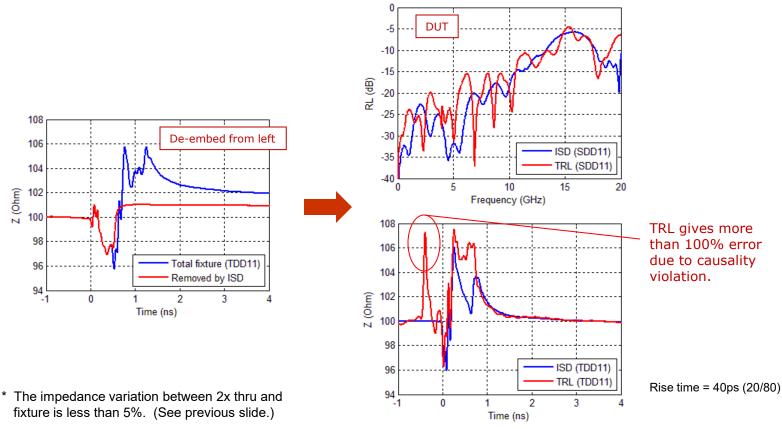
How did ISD do it?

Through numerical optimization, ISD de-embeds fixture's impedance exactly, independent of 2x thru's impedance.



TRL can give huge error in SDD11 even with small impedance variation*

 ISD is able to de-embed fixture's differential impedance with only a single-trace 2x thru.

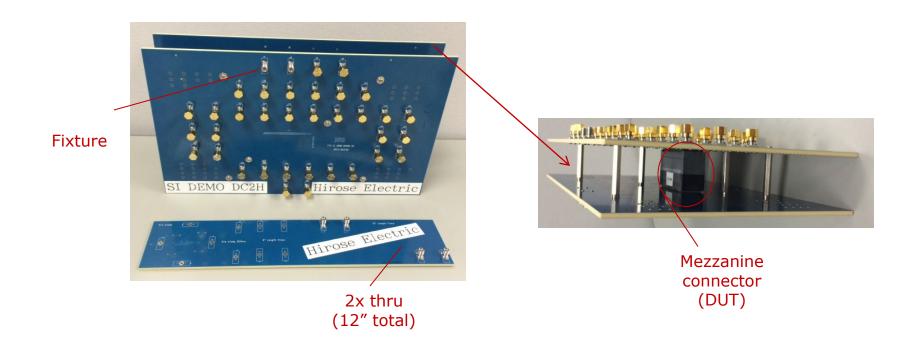






Example 2: Mezzanine connector Extracting DUT from a large board

 TRL is impractical for de-embedding large and coupled lead-ins/outs.

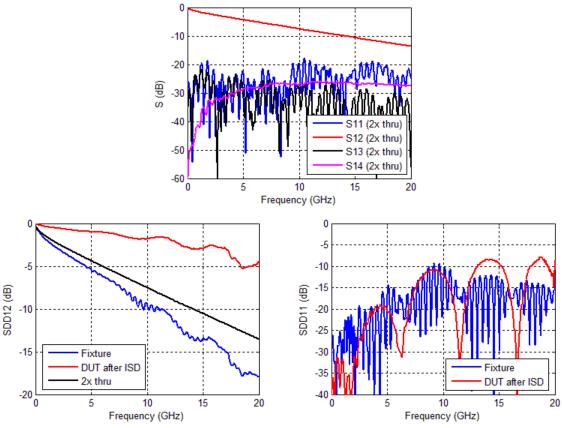






ISD can use a .s4p file of 2x thru for de-embedding

 TRL would have required many long and coupled traces.

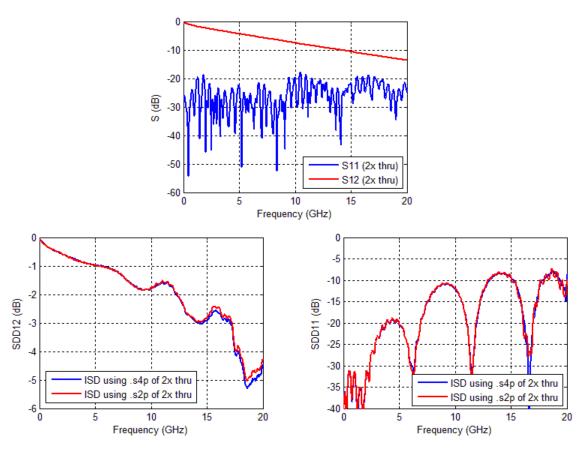






ISD can even use a .s2p file of 2x thru to de-embed crosstalk...

And the results are similar!

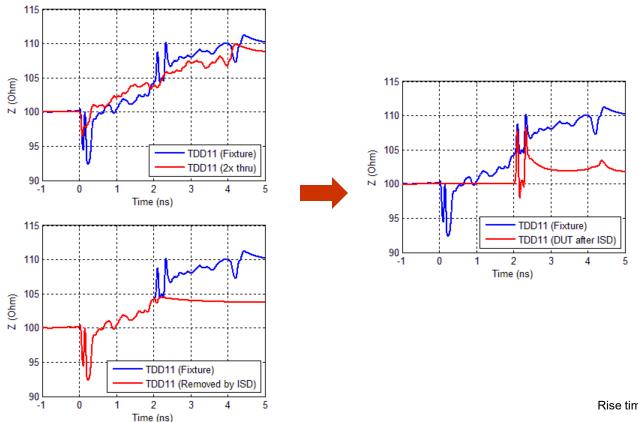


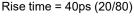




ISD allows a large demo board to double as a characterization board

 ISD de-embeds fixture's impedance regardless of 2x thru's impedance.



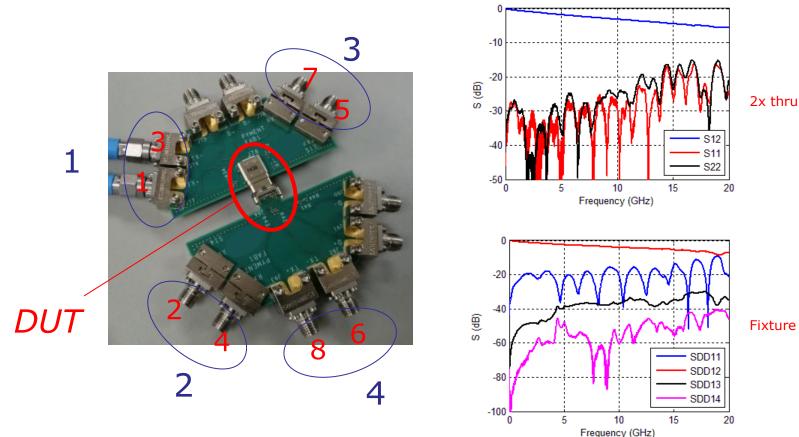






Example 3: USB type C mated connector ISD vs. Tool A

 Good de-embedding is crucial for meeting compliance spec.

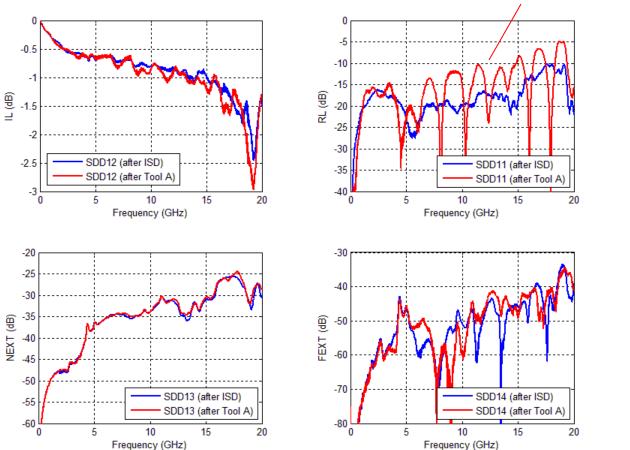






DUT results after ISD and Tool AWhich one is more accurate?

Tool A gives too many ripples in return loss (RL) for such a small DUT.
Non-causal ripples

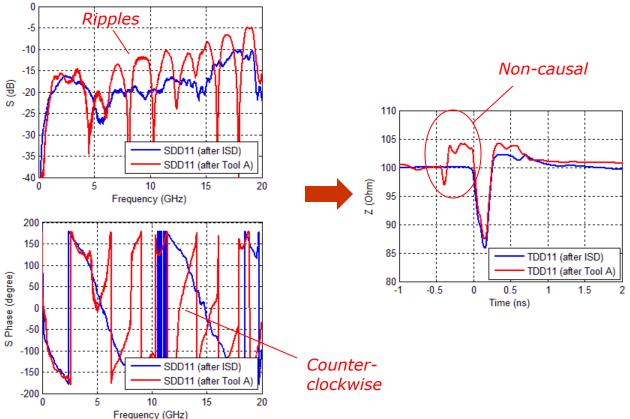






Converting S parameter into TDR/TDT shows non-causality in Tool A results

 Counter-clockwise phase angle is another indication of non-causality.

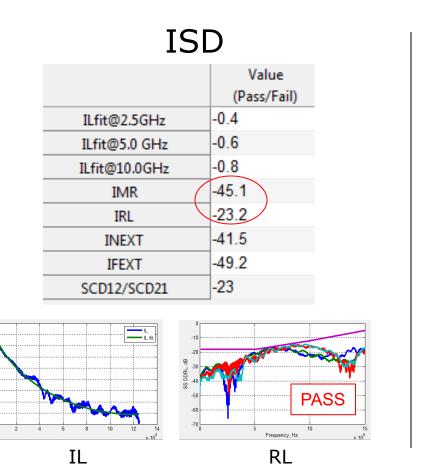




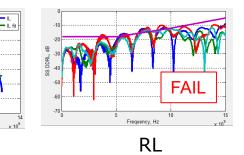


De-embedding affects pass or fail of compliance spec.

ISD improves IMR and IRL (from compliance tool).



Tool A Value Spec (Pass/Fail) -0.6 -0.4ILfit@2.5GHz -0.8 -0.6ILfit@5.0 GHz -1.0ILfit@10.0GHz -0.9-43.7-40 IMR -20.8-18 IRL -41.5-44 INEXT -49.3-44 **IFEXT** -23.2 SCD12/SCD21



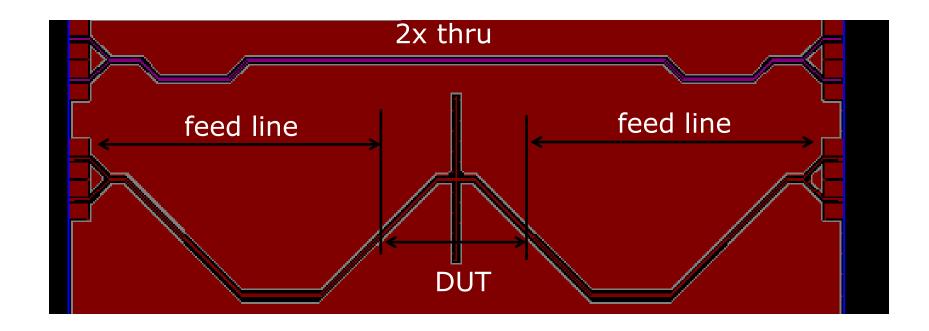




ΤI

Example 4: Resonator *ISD vs. Tool A vs. simulation*

 Good de-embedding is crucial for design verification (i.e., correlation) and improvement.

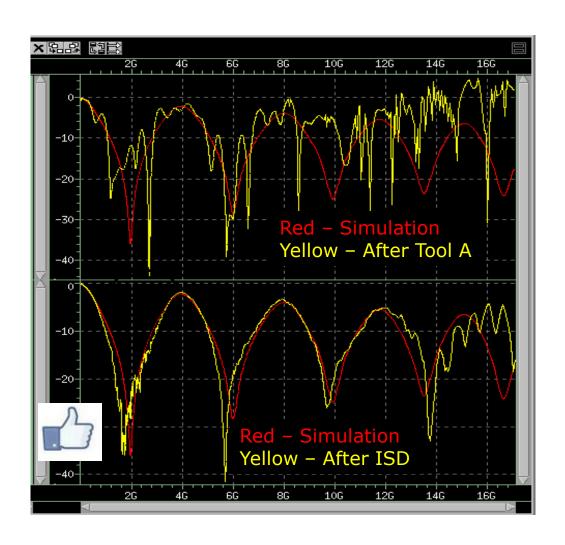






SDD11

ISD correlates with simulation

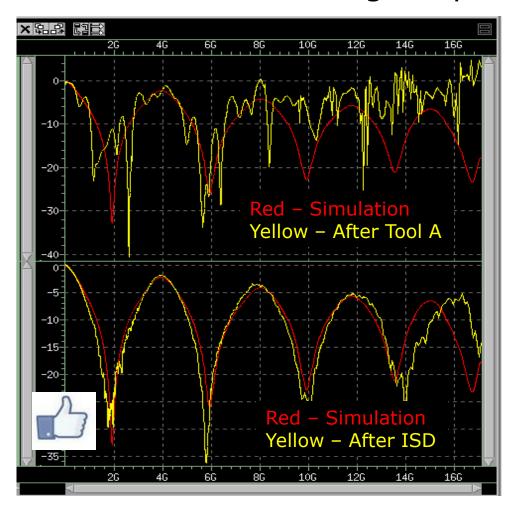






SCC11 ISD correlates with simulation

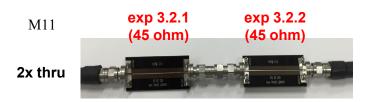
Good correlation is crucial for design improvement.





Example 5: IEEE 370 plug and play kit Use 45 ohm 2x thru to de-embed 50 ohm fixture*

* To mimic possible PCB impedance variation

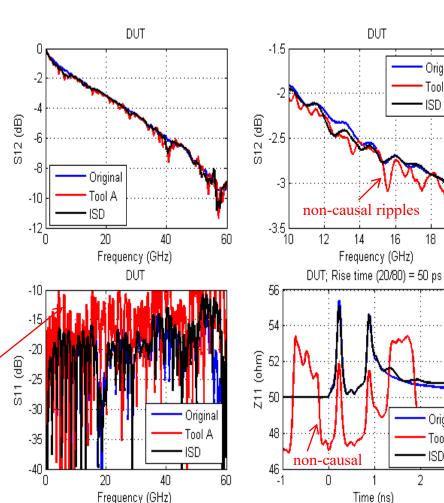


1.85mm M/M + M/F Adapter 1.85mm M/M + M/F Adapter

 $^{
m M16}$ exp 3.1.1 exp 3.1.2 (50 ohm) (50 ohm) M1

FIXTURE A exp 4.1.1 6 cm microstrip **FIXTURE B** (DUT)

Inaccurate RL is not suitable for DK/DF/SR extraction.







Original

Tool A

ISD

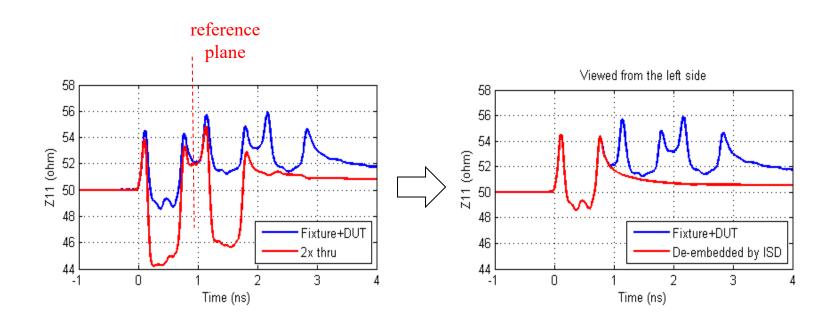
2

Original

Tool A ISD.

2x thru vs. fixture impedance

ISD de-embeds fixture's impedance, not 2x thru's impedance.

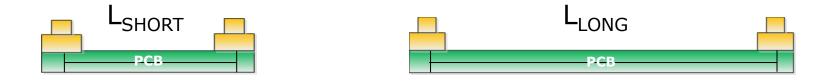






Example 6: PCB trace attenuation ISD vs. eigenvalue (Delta-L)

 De-embed short trace (+ launch) from long trace (+ launch) to get trace-only attenuation.

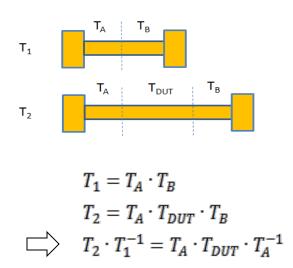






Eigenvalue solution: not de-embedding For calculating trace attenuation only

- Convert S to T for short and long trace structures
- Assume the left (and right) sides of short and long trace structures are identical
- Assume DUT is uniform transmission line
- Trace-only attenuation is written in one equation.

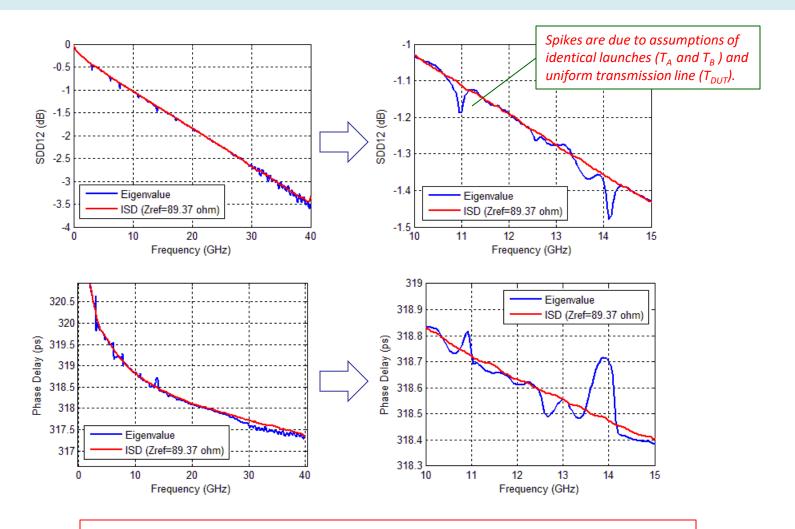


For uniform transmission line:





Case 1: 2" (=7"-5") trace attenuation Eigenvalue solution is prone to spikes

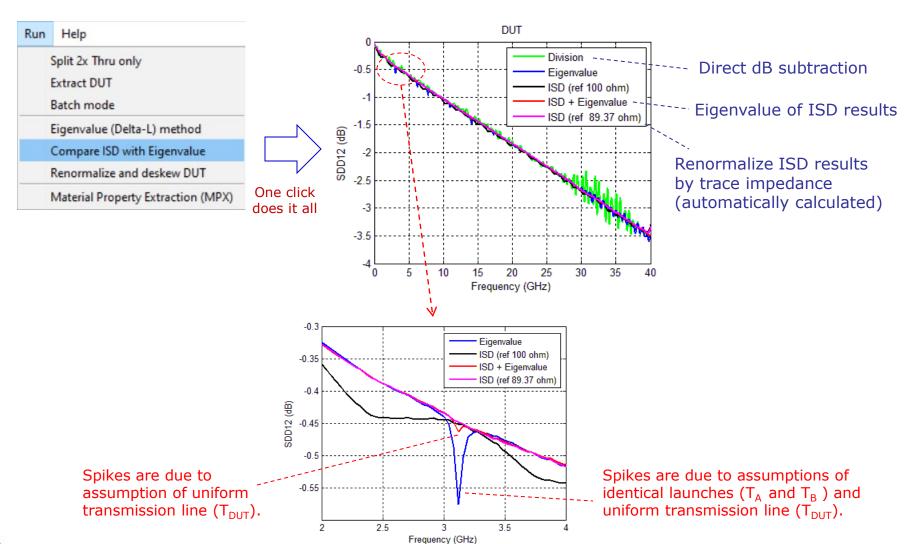


ISD's spike-free results help DK and DF extraction later.





One click compares ISD with eigenvalue and more...

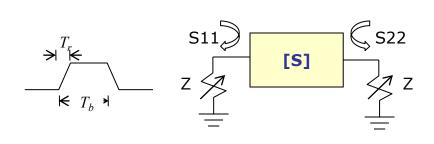






How to define trace impedance PCB trace is non-uniform transmission line

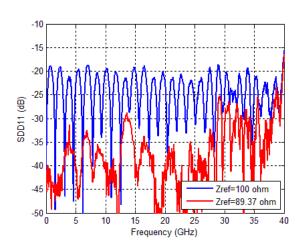
Define impedance by minimal RL*

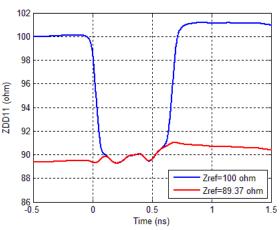


Minimize:

$$\varphi = \int_{f_{\min}}^{f_{\max}} \left\{ \left| S_{11}(f) \right|^2 + \left| S_{22}(f) \right|^2 \right\} \cdot \left| w(f) \right|^2 df$$

$$w(f) = \frac{\sin(\pi f T_r)}{\pi f T_r} \cdot \frac{\sin(\pi f T_b)}{\pi f T_b}$$





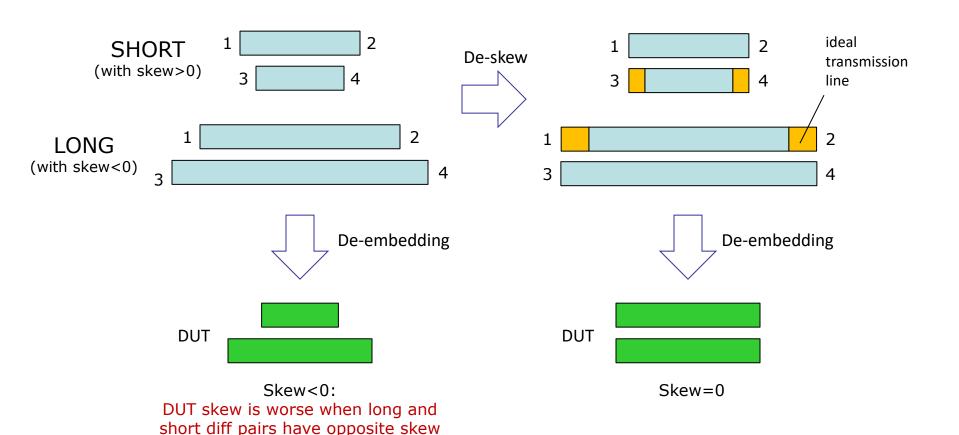




^{*} J. Balachandran, K. Cai, Y. Sun, R. Shi, G. Zhang, C.C. Huang and B. Sen, "Aristotle: A fully automated SI platform for PCB material characterization," DesignCon 2017, 01/31-02/02/2017, Santa Clara, CA.

Skewless de-embedding

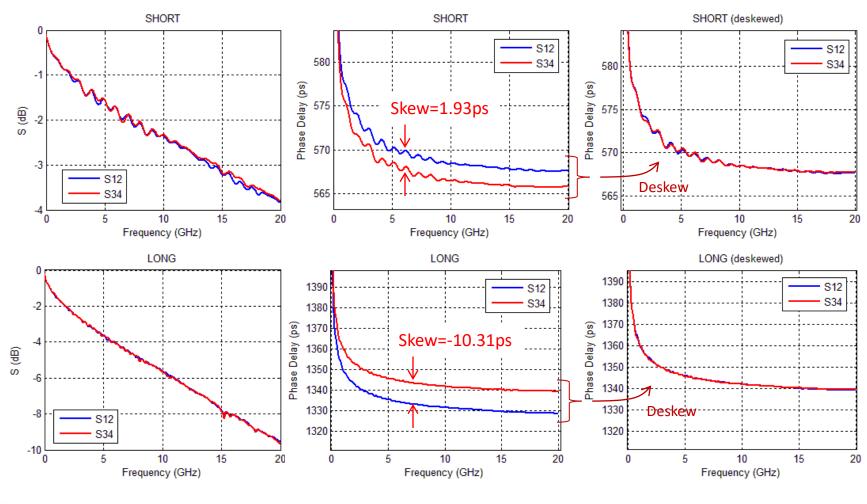
Pad ideal transmission line to de-skew.







ISD optionally automates de-skewing of raw data

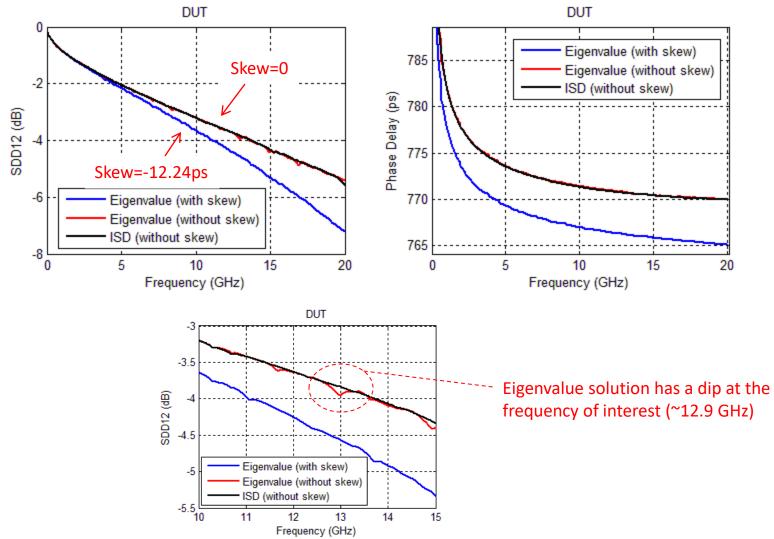








Case 2: Extracted trace attenuation can be very different with or without skew

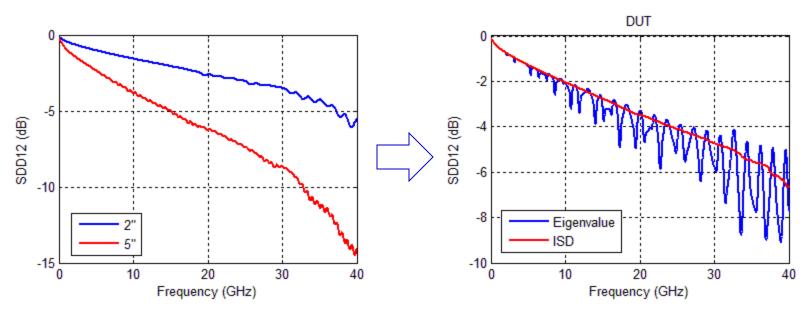






Case 3: Eigenvalue (Delta-L) solution becomes unstable in this case, but why?



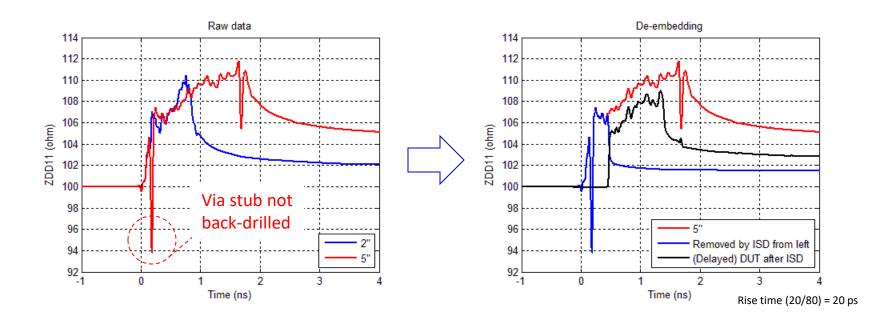






TDR of raw data reveals why... 2" structure was back-drilled but 5" was not

- Eigenvalue solution assumes 2" and 5" structures have identical launches.
- ISD de-embeds 5" structure's launch correctly.

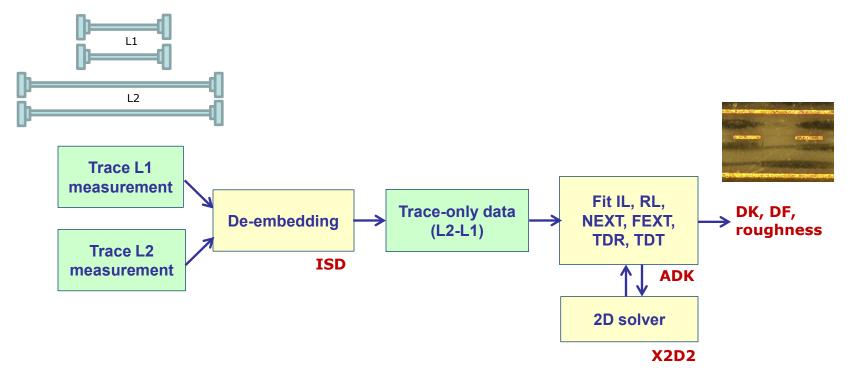


ISD saves \$\$\$ and time for not spinning another board.



Example 7: Material property extraction *DK, DF and roughness*

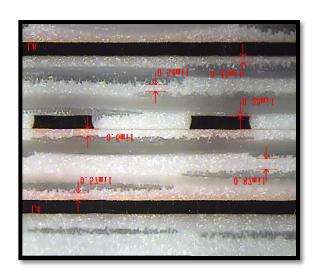
 Self consistent approach to extract DK, DF and roughness by matching all IL, RL, NEXT, FEXT and TDR/TDT of de-embedded trace-only data.

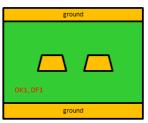


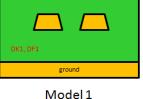


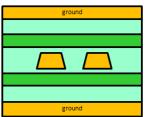


Models for cross section

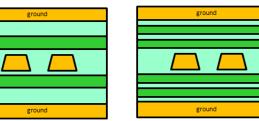




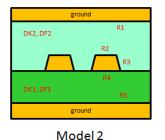


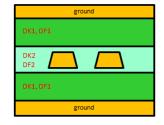


Model 4



Optimized variables: DK1, DF1, DK2, DF2 R1, R2, R3, R4, R5 (roughness) Metal width and spacing





Model 3



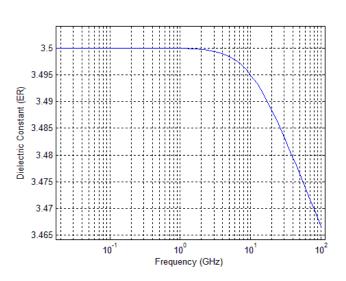


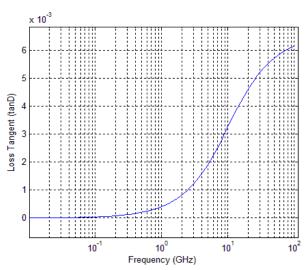


Causal dielectric model

- Wideband Debye (or Djordjevic-Sarkar) model
 - Need only four variables: ε_{∞} , $\Delta \varepsilon$, m_1 , m_2

$$\varepsilon = \varepsilon_{\infty} + \Delta \varepsilon \cdot \frac{1}{m_2 - m_1} \cdot \log_{10} \left(\frac{10^{m_2} + i \cdot f}{10^{m_1} + i \cdot f} \right)$$
$$= \varepsilon_r \cdot (1 - i \cdot \tan \delta)$$





$$\varepsilon_{\infty} = 3.35$$
 , $\Delta \varepsilon = 0.15$, $m_1 = 10$, $m_2 = 14.5$





Surface roughness model

• Effective conductivity (by G. Gold & K. Helmreich at DesignCon 2014) needs only two variables: σ_{bulk} , R_q

Parameter	Description	Standard
R_q	root mean square	DIN EN ISO 4287
R_a	arithmetic average	DIN EN ISO 4287, ANSI B 46.1
R_k	core roughness depth	DIN EN ISO 13565
R_z	average surface roughness	DIN EN ISO 4287

$$\sigma(x) = \sigma_{bulk} \cdot CDF(x) = \sigma_{bulk} \cdot \int_{-\infty}^{x} PDF(x) du = \sigma_{bulk} \cdot \int_{-\infty}^{x} e^{-\frac{u^{2}}{2R_{q}^{2}}} du$$

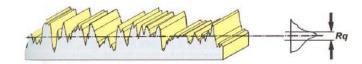
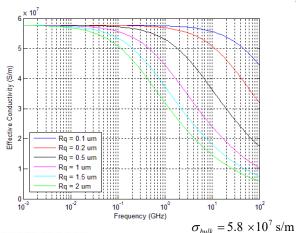


Table 1: Statistical parameters to describe surface roughness

• Numerically solving $\nabla^2 \overline{B} - j\omega\mu\sigma\overline{B} + \frac{\nabla\sigma}{\sigma} \times (\nabla \times \overline{B}) = 0$ and equating power to that of smooth surface gives σ_{eff}



- ❖ Simple
- Work well with field solver
- Give effect of roughness on all IL, RL, NEXT and FEXT





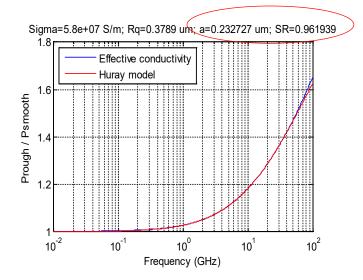
Convert effective conductivity to Huray model

Huray model

$$\frac{P_{rough}}{P_{smooth}} \approx 1 + \frac{3}{2} \cdot SR \cdot \left(\frac{1}{1 + \frac{\delta(f)}{a} + \frac{1}{2} \left(\frac{\delta(f)}{a} \right)^2} \right)$$

$$\delta(f) = \sqrt{\frac{1}{\pi f \mu \sigma}} \; ; \; a = \text{radius} \; ; \; SR = \text{surface ratio}$$

• Curvefit* P_{rough} / P_{smooth} to convert σ_{bulk} , R_q to a, SR

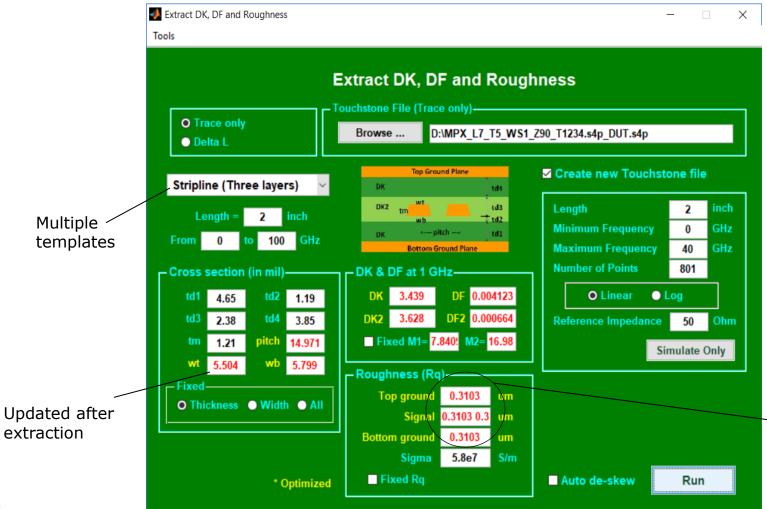


*Automated in ADK





DK/DF/SR extraction (from ADK)

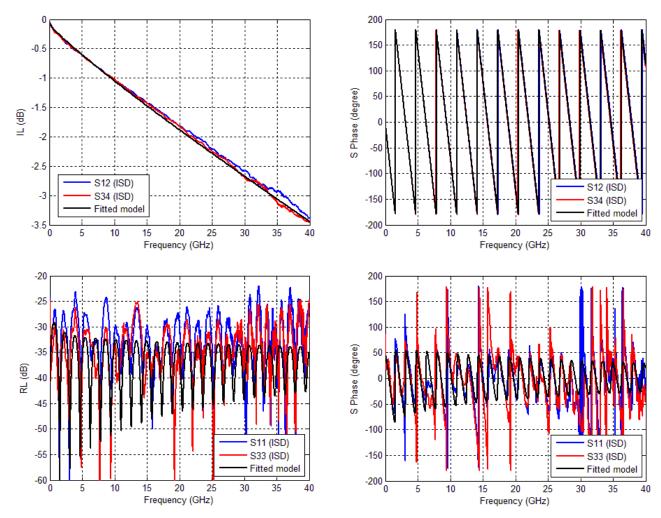


Different roughness for each surface





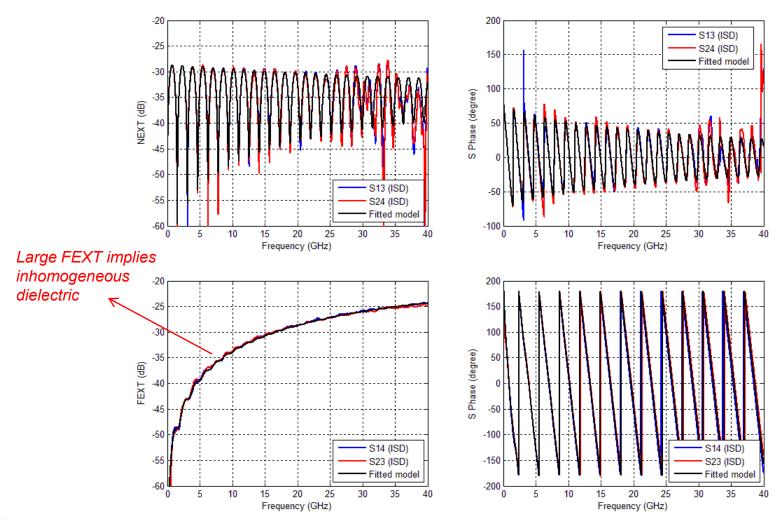
Matching IL and RL







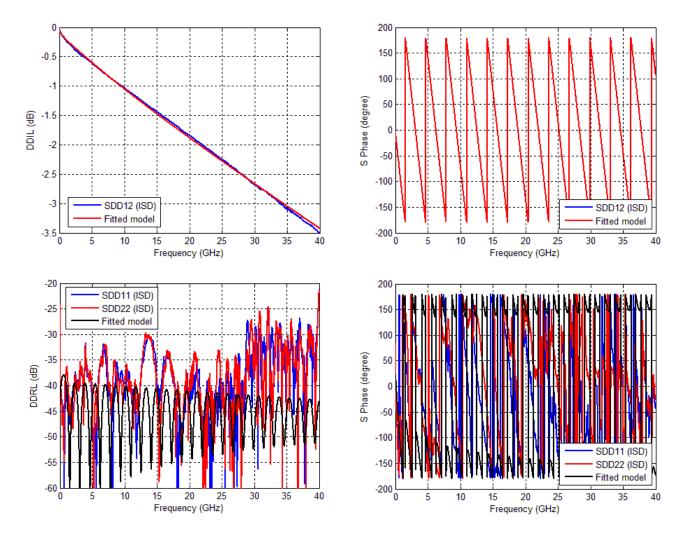
Matching NEXT and FEXT







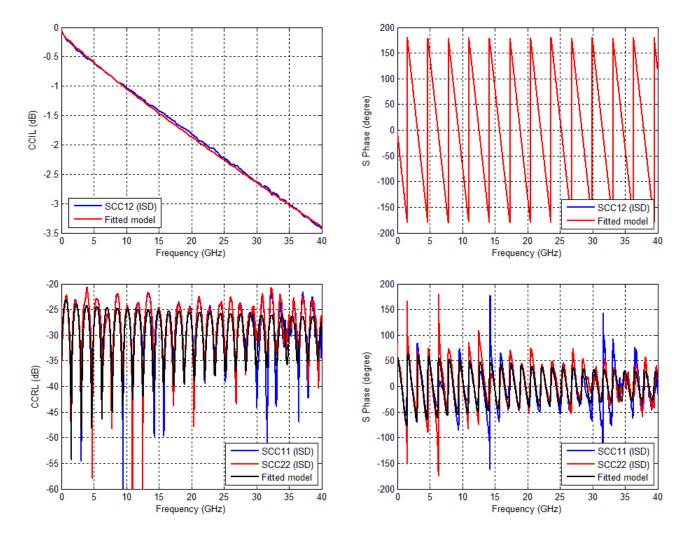
Matching DDIL and DDRL







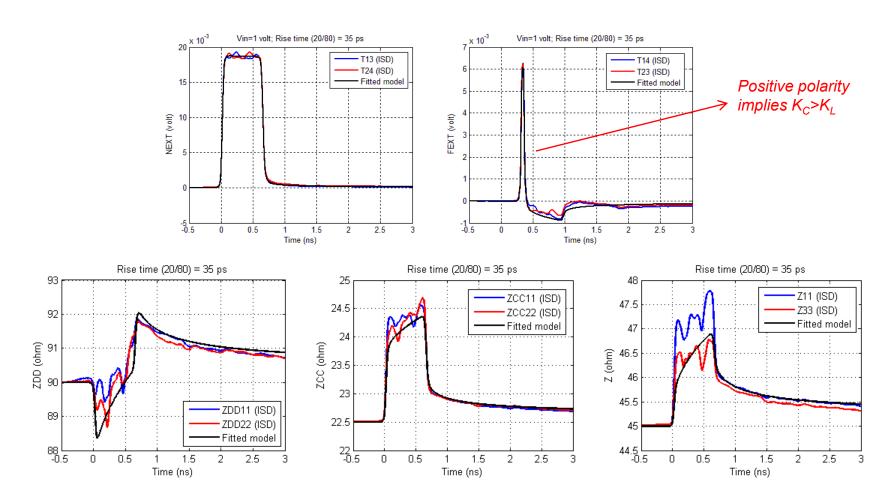
Matching CCIL and CCRL







Matching TDT and TDR

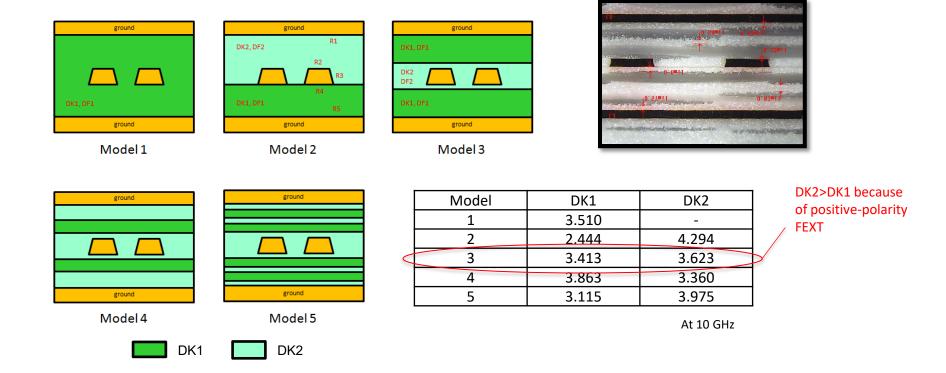






Comparison of Models 1 to 5

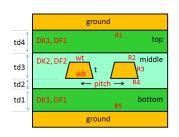
 Model 1 cannot match FEXT. Models 2 to 5 can match all IL, RL, NEXT, FEXT and TDR/TDT very well.



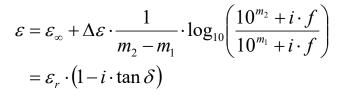


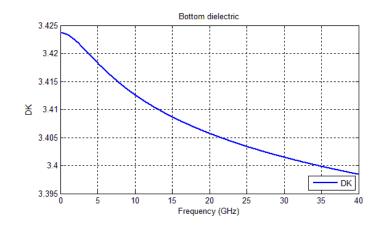


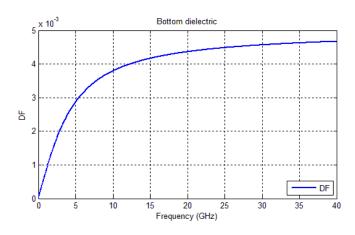
Extracted DK1 and DF1 Model 3



$$\varepsilon_{\infty} = 3.27929$$
 $\Delta \varepsilon = 0.144348$
 $m1 = 9.58619$
 $m2 = 15.4109$



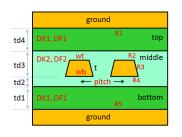




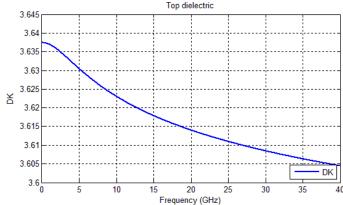




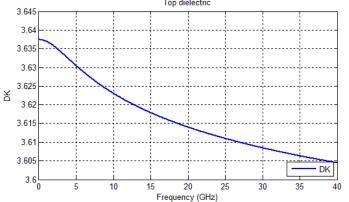
Extracted DK2 and DF2 Model 3

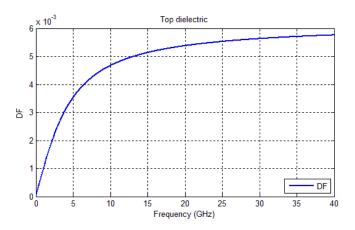


$$\varepsilon_{\infty} = 3.46724$$
 $\Delta \varepsilon = 0.170196$
 $m1 = 9.58715$
 $m2 = 14.8352$



$$\varepsilon = \varepsilon_{\infty} + \Delta \varepsilon \cdot \frac{1}{m_2 - m_1} \cdot \log_{10} \left(\frac{10^{m_2} + i \cdot f}{10^{m_1} + i \cdot f} \right)$$
$$= \varepsilon_r \cdot (1 - i \cdot \tan \delta)$$

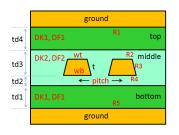






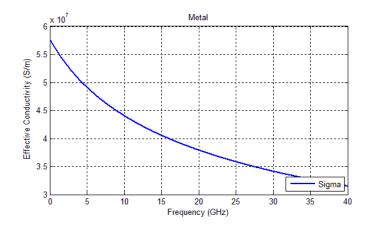


Extracted effective conductivity *Model 3*



$$\sigma = 5.8 \times 10^7 \text{ S/m}$$

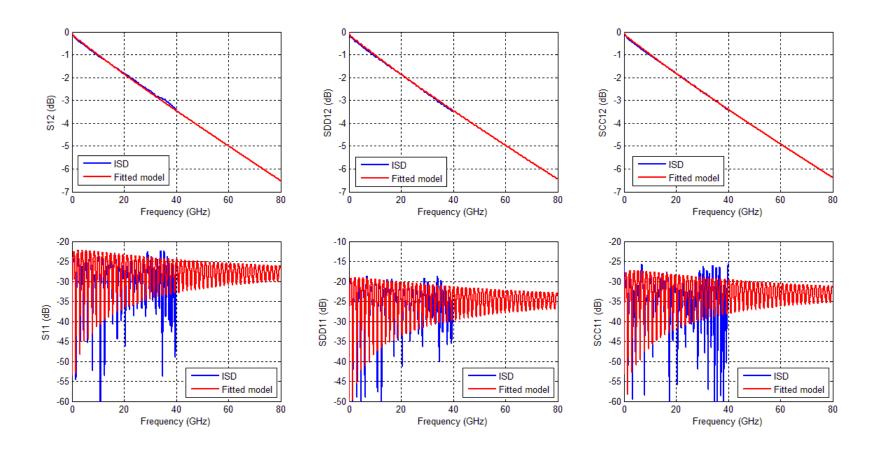
 $R_q = 0.324321 \,\mu\text{m}$







Length- and frequency-scalable models can now be created.







Summary

- Accurate de-embedding is crucial for design verification, compliance testing and PCB material property (DK, DF, roughness) extraction.
- Traditional de-embedding methods can give noncausal errors in device-under-test (DUT) results if the test fixture and calibration structure have different impedances.
- In-Situ De-embedding (ISD) addresses such impedance differences through software instead of hardware, thereby improving de-embedding accuracy while reducing hardware costs.





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